TOSHIBA Field Effect Transistor Silicon N-Channel MOS Type (U-MOSIV)

# **TPCA8026**

Lithium-Ion Battery Applications Notebook PC Applications Portable Equipment Applications

- Small footprint due to a small and thin package
- Low drain-source ON-resistance:  $RDS(ON) = 1.8 \text{ m}\Omega \text{ (typ.)}$
- High forward transfer admittance:  $|Y_{fs}| = 100 \text{ S (typ.)}$
- Low leakage current:  $IDSS = 10 \mu A (max) (VDS = 30 V)$
- Enhancement mode:  $V_{th} = 1.3$  to 2.5 V ( $V_{DS} = 10$  V,  $I_{D} = 1$  mA)

## **Absolute Maximum Ratings (Ta = 25°C)**

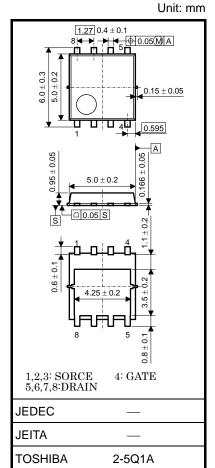
Characte	eristic	Symbol	Rating	Unit
Drain-source voltage		$V_{DSS}$	30	V
Drain-gate voltage (R	$k_{GS} = 20 \text{ k}\Omega$	$V_{DGR}$	30	V
Gate-source voltage		V <sub>GSS</sub>	±20	V
Due's some of	DC (Note 1)	I <sub>D</sub>	45	А
Drain current	Pulsed (Note 1)	I <sub>DP</sub>	135	A
Drain power dissipati	on (Tc = 25°C)	P <sub>D</sub>	45	W
Drain power dissipati	on (t = 10 s) (Note 2a)	P <sub>D</sub>	2.8	W
Drain power dissipati	on (t = 10 s) (Note 2b)	P <sub>D</sub>	1.6	W
Single-pulse avalance	he energy (Note 3)	E <sub>AS</sub>	263	mJ
Avalanche current		I <sub>AR</sub>	45	Α
Repetitive avalanche	energy c = 25°C) (Note 4)	E <sub>AR</sub>	3.4	mJ
Channel temperature		T <sub>ch</sub>	150	°C
Storage temperature	range	T <sub>stg</sub>	-55 to 150	°C

Note: For Notes 1 to 4, refer to the next page.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Ha

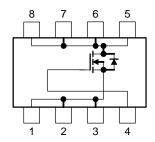
reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

This transistor is an electrostatic-sensitive device. Handle with care.



Weight: 0.069 g (typ.)

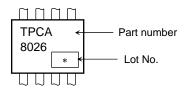
### **Circuit Configuration**



#### **Thermal Characteristics**

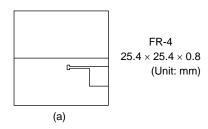
Characteristic	Symbol	Max	Unit
Thermal resistance, channel to case $(Tc = 25^{\circ}C)$	R <sub>th (ch-c)</sub>	2.78	°C/W
Thermal resistance, channel to ambient $(t=10 \; s) \eqno(Note \; 2a)$	R <sub>th (ch-a)</sub>	44.6	°C/W
Thermal resistance, channel to ambient (t = 10 s) (Note 2b)	R <sub>th (ch-a)</sub>	78.1	°C/W

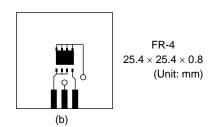
# Marking (Note 5)



Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: (a) Device mounted on a glass-epoxy board (b) Device mounted on a glass-epoxy board (b)

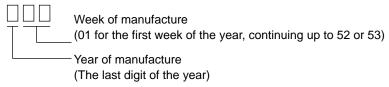




Note 3:  $V_{DD} = 24 \text{ V}$ ,  $T_{ch} = 25^{\circ}\text{C}$  (initial), L = 0.1 mH,  $I_{AR} = 45 \text{ A}$ 

Note 4: Repetitive rating: pulse width limited by maximum channel temperature

Note 5: \* Weekly code: (Three digits)



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TPCA8026



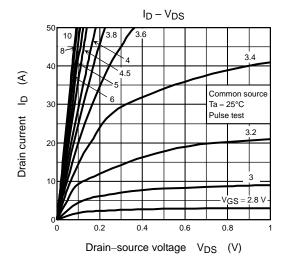
# **Electrical Characteristics (Ta = 25°C)**

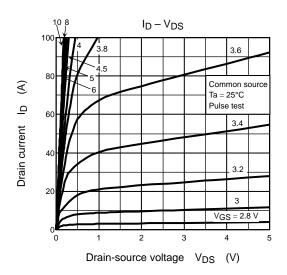
Characteristic		Symbol	Test Condition	Min	Тур.	Max	Unit	
Gate leakage current		I <sub>GSS</sub>	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±100	nA	
Drain cutoff current		I <sub>DSS</sub>	V <sub>DS</sub> = 30 V, V <sub>GS</sub> = 0 V	_	_	10	μА	
Drain-source breakdown voltage		V (BR) DSS	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	30	_	_	V	
Diam-source bre	akuowii voitage	V (BR) DSX	$I_D = 10 \text{ mA}, V_{GS} = -20 \text{ V}$	10	- ±100 - 10 30	V		
Gate threshold v	oltage	$V_{th}$	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1 mA	1.3	_	2.5	V	
Drain-source ON-resistance		Б	V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 23 A	_	2.7	4.5	- mΩ	
		R <sub>DS</sub> (ON)	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 23 A	_	1.8	2.2		
Forward transfer	admittance	Y <sub>fs</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 23 A	50	100	_	S	
Input capacitance		C <sub>iss</sub>	V <sub>DS</sub> = 10 V, V <sub>GS</sub> = 0 V, f = 1 MHz	_	4200	_	pF	
Reverse transfer	Reverse transfer capacitance			_	1000	_		
Output capacitance		C <sub>oss</sub>		_	1400	_		
Switching time	Rise time	t <sub>r</sub>	V <sub>GS</sub> 10 V	_	15	_	- ns	
	Turn-on time	t <sub>on</sub>		_	30	_		
	Fall time	tf		_	36	_		
	Turn-off time	t <sub>off</sub>	V <sub>DD</sub> ≈ 15 V Duty ≤ 1%, t <sub>W</sub> = 10 μs	_	111	_		
Total gate charge (gate-source plus gate-drain)		Qg		_	113	_	nC	
Gate-source charge 1		Q <sub>gs1</sub>	$V_{DD} \approx 24 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 45 \text{ A}$	_	13	_		
Gate-drain ("miller") charge		Q <sub>gd</sub>		_	42	_		

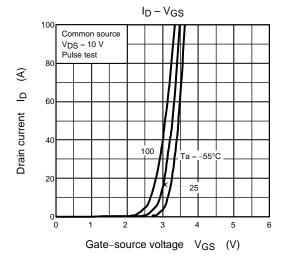
# **Source-Drain Ratings and Characteristics (Ta = 25°C)**

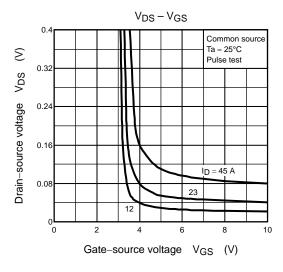
Characteristic		Symbol	Test Condition	Min	Тур.	Max	Unit	
Drain reverse current	Pulse	(Note 1)	$I_{DRP}$	_	_	_	135	Α
Forward voltage (diode)			$V_{DSF}$	$I_{DR} = 45 \text{ A}, V_{GS} = 0 \text{ V}$	_	_	-1.2	V

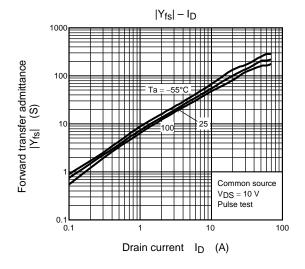
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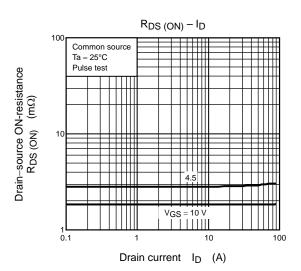




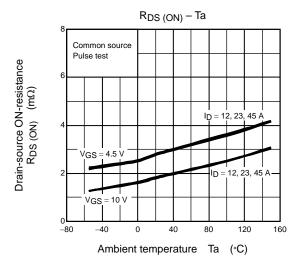


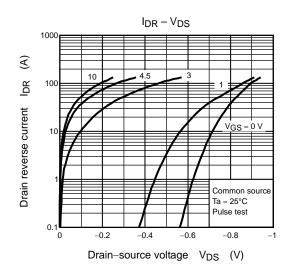


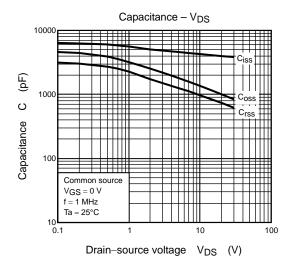


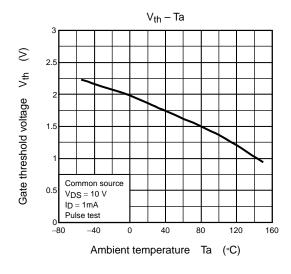


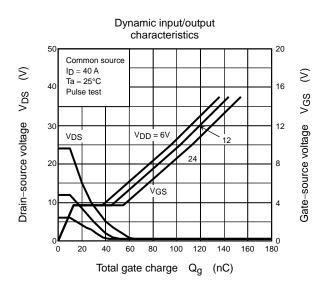
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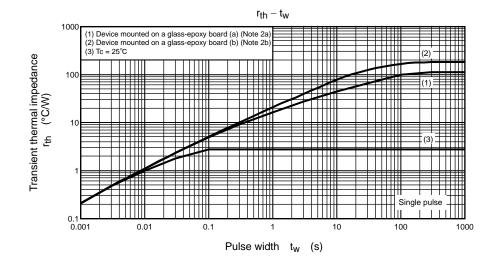


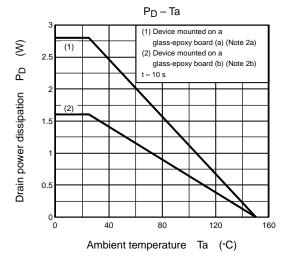


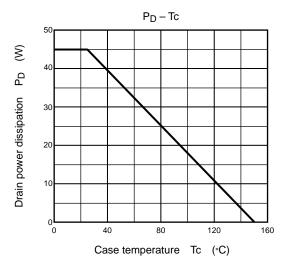


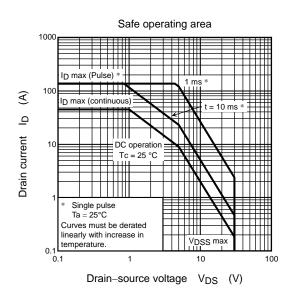


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